

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

SSM6P15FE

High Speed Switching Applications

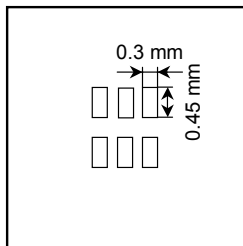
Analog Switch Applications

- Small package
- Low ON resistance : $R_{on} = 12 \Omega$ (max) (@ $V_{GS} = -4 V$)
: $R_{on} = 32 \Omega$ (max) (@ $V_{GS} = -2.5 V$)

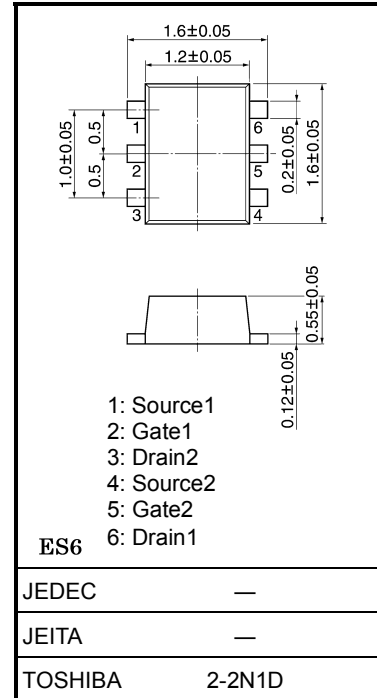
Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit
Drain-Source voltage		V_{DS}	-30	V
Gate-Source voltage		V_{GSS}	± 20	V
Drain current	DC	I_D	-100	mA
	Pulse	I_{DP}	-200	
Drain power dissipation (Ta = 25°C)		P_D (Note)	150	mW
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	-55~150	°C

Note: Total rating, mounted on FR4 board
(25.4 mm × 25.4 mm × 1.6 t, Cu Pad: $0.135 \text{ mm}^2 \times 6$)

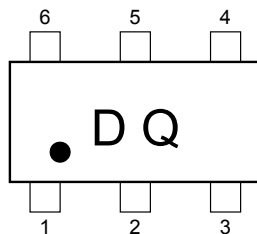


Unit: mm

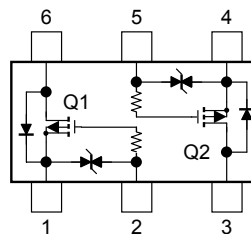


Weight: 0.003g(typ.)

Marking



Equivalent Circuit (top view)



Handling Precaution

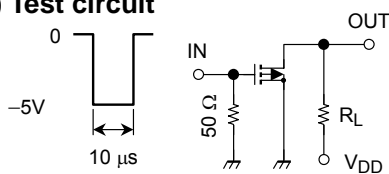
When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristic	Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT	
Gate leakage current	I_{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$	—	—	± 1	μA	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	$I_D = -0.1 \text{ mA}, V_{GS} = 0$	-30	—	—	V	
Drain cut-off current	I_{DSS}	$V_{DS} = -30 \text{ V}, V_{GS} = 0$	—	—	-1	μA	
Gate threshold voltage	V_{th}	$V_{DS} = -3 \text{ V}, I_D = -0.1 \text{ mA}$	-1.1	—	-1.7	V	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = -3 \text{ V}, I_D = -10 \text{ mA}$	20	—	—	mS	
Drain-Source ON resistance	$R_{DS(ON)}$	$I_D = -10 \text{ mA}, V_{GS} = -4 \text{ V}$	—	8	12	Ω	
		$I_D = -1 \text{ mA}, V_{GS} = -2.5 \text{ V}$	—	14	32		
Input capacitance	C_{iss}	$V_{DS} = -3 \text{ V}, V_{GS} = 0, f = 1 \text{ MHz}$	—	9.1	—	pF	
Reverse transfer capacitance	C_{rss}		—	3.5	—	pF	
Output capacitance	C_{oss}		—	8.6	—	pF	
Switching time	Turn-on time	t_{on}	$V_{DD} = -5 \text{ V}, I_D = -10 \text{ mA},$ $V_{GS} = 0 \sim -5 \text{ V}$	—	65	—	ns
	Turn-off time	t_{off}		—	175	—	

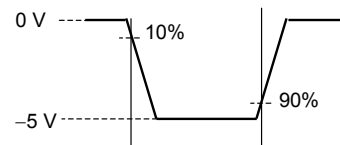
Switching Time Test Circuit

(a) Test circuit

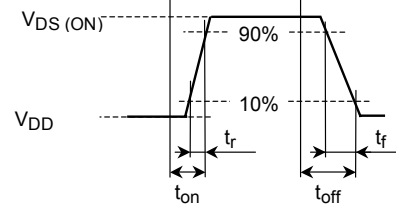


$V_{DD} = -5 \text{ V}$
 Duty $\leq 1\%$
 V_{IN} : $t_r, t_f < 5 \text{ ns}$
 $(Z_{out} = 50 \Omega)$
 Common Source
 $T_a = 25^\circ\text{C}$

(b) V_{IN}



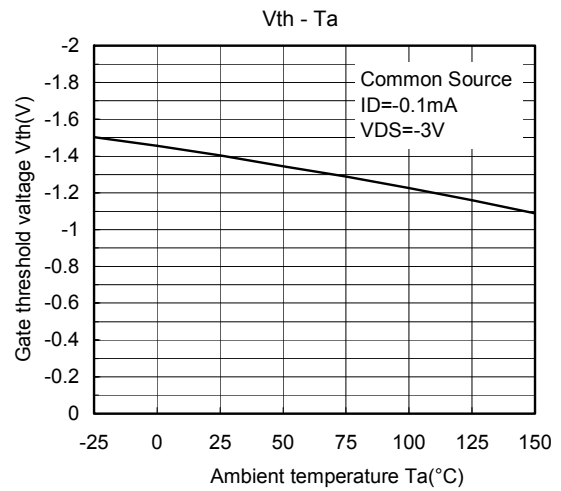
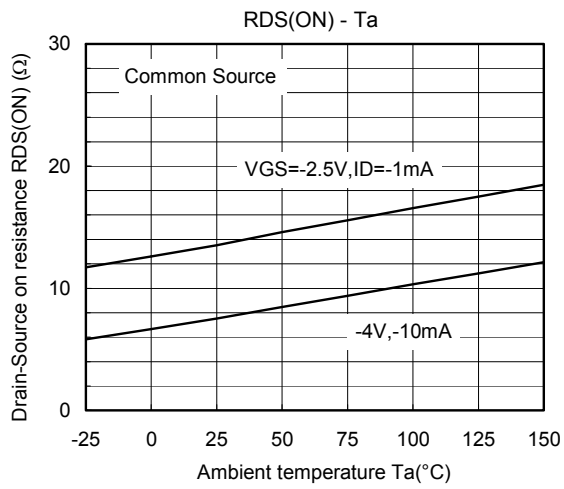
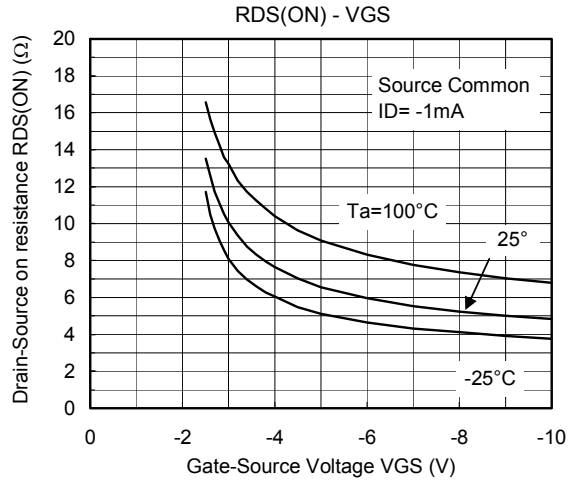
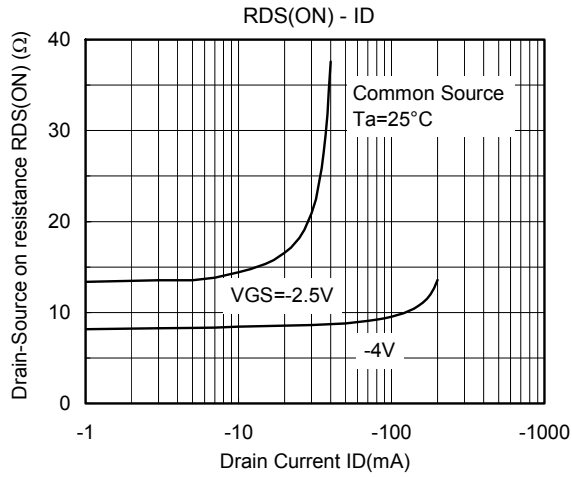
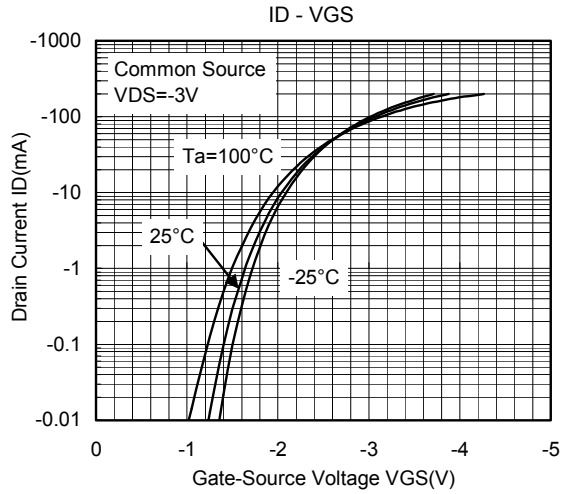
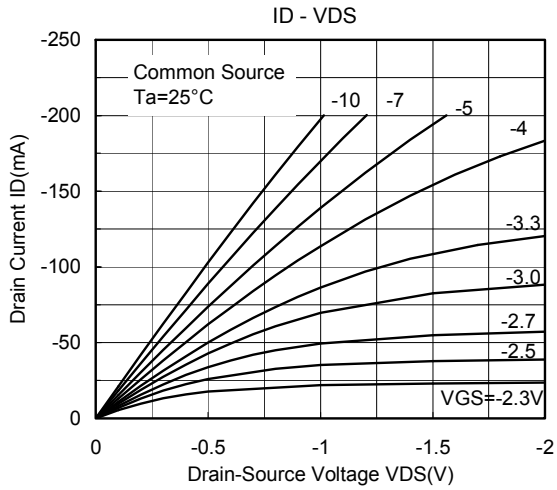
(c) V_{OUT}

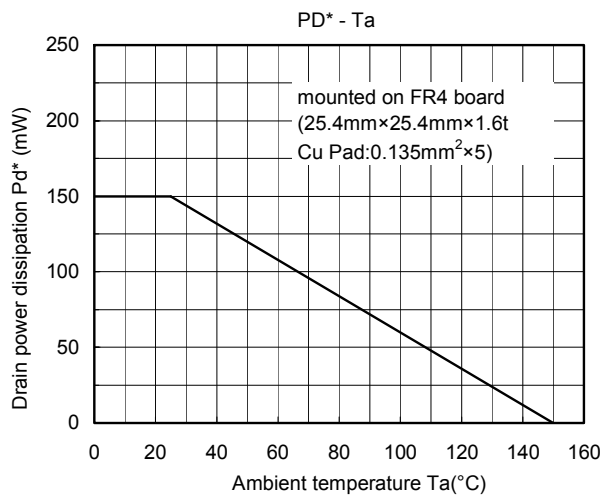
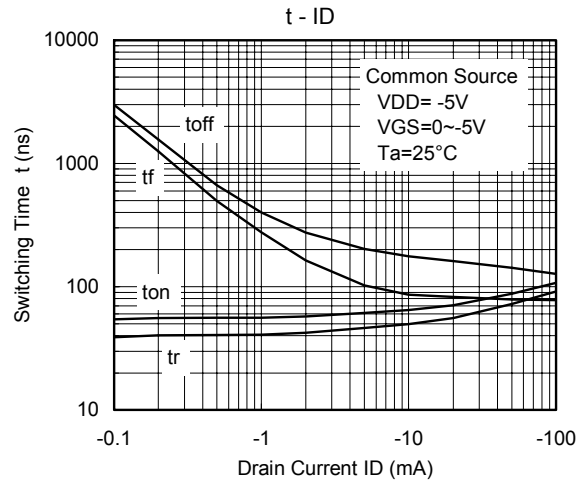
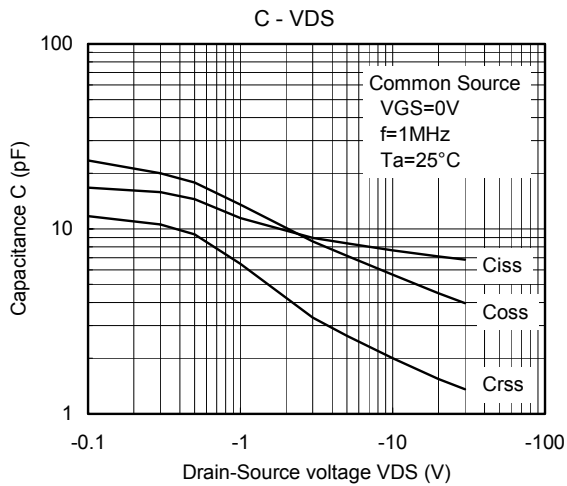
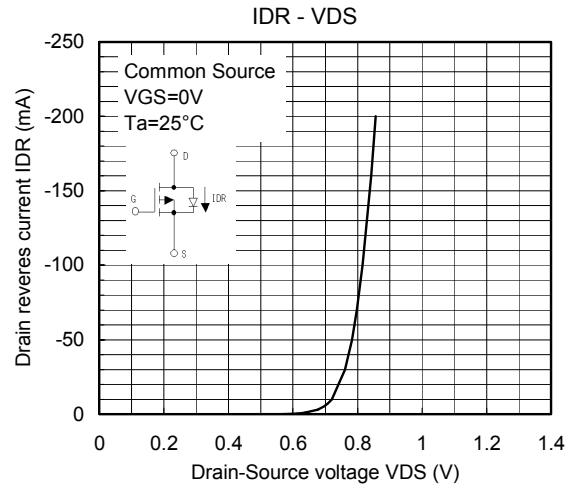
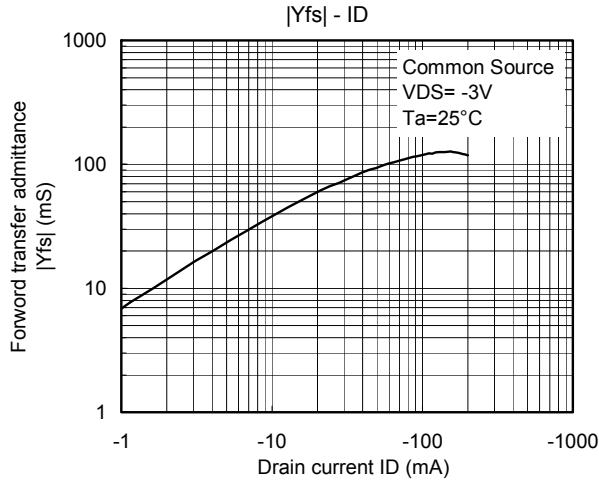


Precaution

V_{th} can be expressed as voltage between gate and source when low operating current value is $I_D = -100 \mu\text{A}$ for this product. For normal switching operation, $V_{GS(ON)}$ requires higher voltage than V_{th} and $V_{GS(OFF)}$ requires lower voltage than V_{th} . (Relationship can be established as follows: $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$)

Please take this into consideration for using the device. V_{GS} recommended voltage of -2.5 V or higher to turn on this product.





*: Total Rating

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